



AF/2811

Docket No.: 57454-162

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PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

: **RESPONSE UNDER 37 CFR 1.116**
: **EXPEDITED PROCEDURE**

Yukio MAKI

:

Serial No.: 09/909,975

: Group Art Unit: 2811

Filed: July 23, 2001

: Examiner: S. Gebremariam

For: SEMICONDUCTOR DEVICE AND MANUFACTURING METHOD OF THE SAME

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AMENDMENT UNDER 37 CFR §1.116

Box AF
Commissioner for Patents
Washington, DC 20231

Sir:

The following Amendment and Remarks are submitted in response to the Office Action
dated December 12, 2002, pursuant to the provisions of 37 C.F.R. §1.116.

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IN THE CLAIMS:

Please amend claim 1 as follows.

1. (Amended) A semiconductor device, comprising:

a semiconductor substrate including an active region and an isolation region; and

a gate electrode formed on said active region with an insulating film interposed

therebetween, wherein:

a surface of said active region is entirely rounded so as to be inclined downward toward
said isolation region;

said semiconductor device includes an SRAM (Static Random Access Memory);